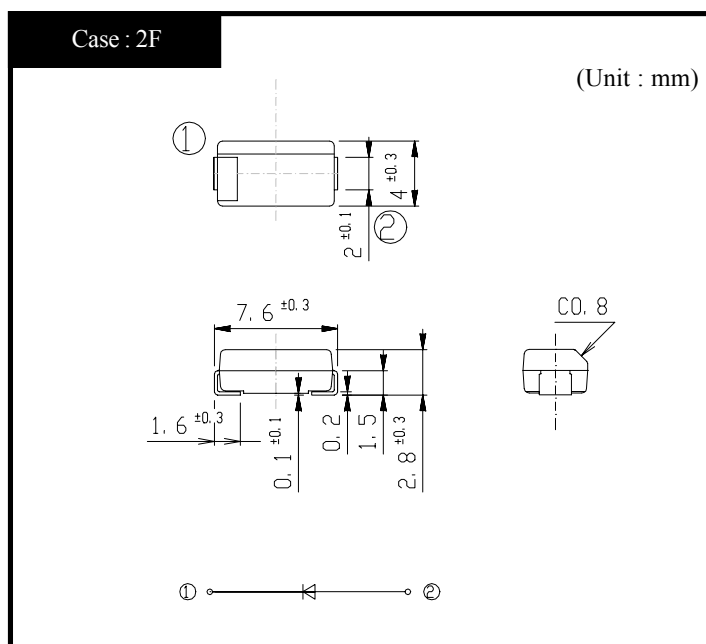


# KP10N14

### OUTLINE DIMENSIONS



### RATINGS

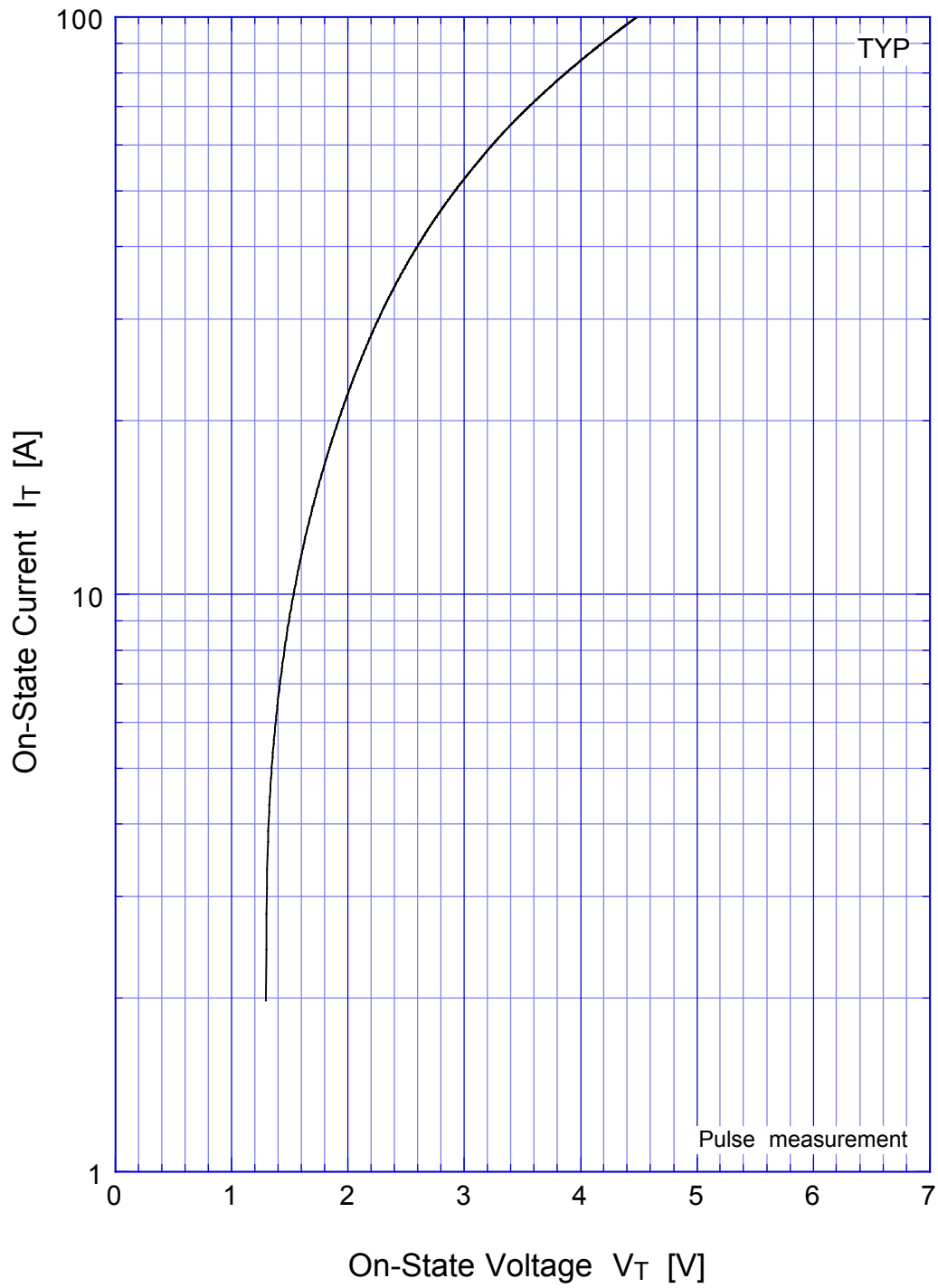
#### ● Absolute Maximum Ratings

Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	$T_{stg}$		-40~125	°C
Junction Temperature	$T_j$		125	°C
Maximum Off-State Voltage	$V_{DRM}$		120	V
Surge On-State Current	$I_{TSM}$	10/1000 $\mu$ s, Non-repetitive	100	A
		10/200 $\mu$ s, Non-repetitive	150	
		8/20 $\mu$ s, Non-repetitive	250	

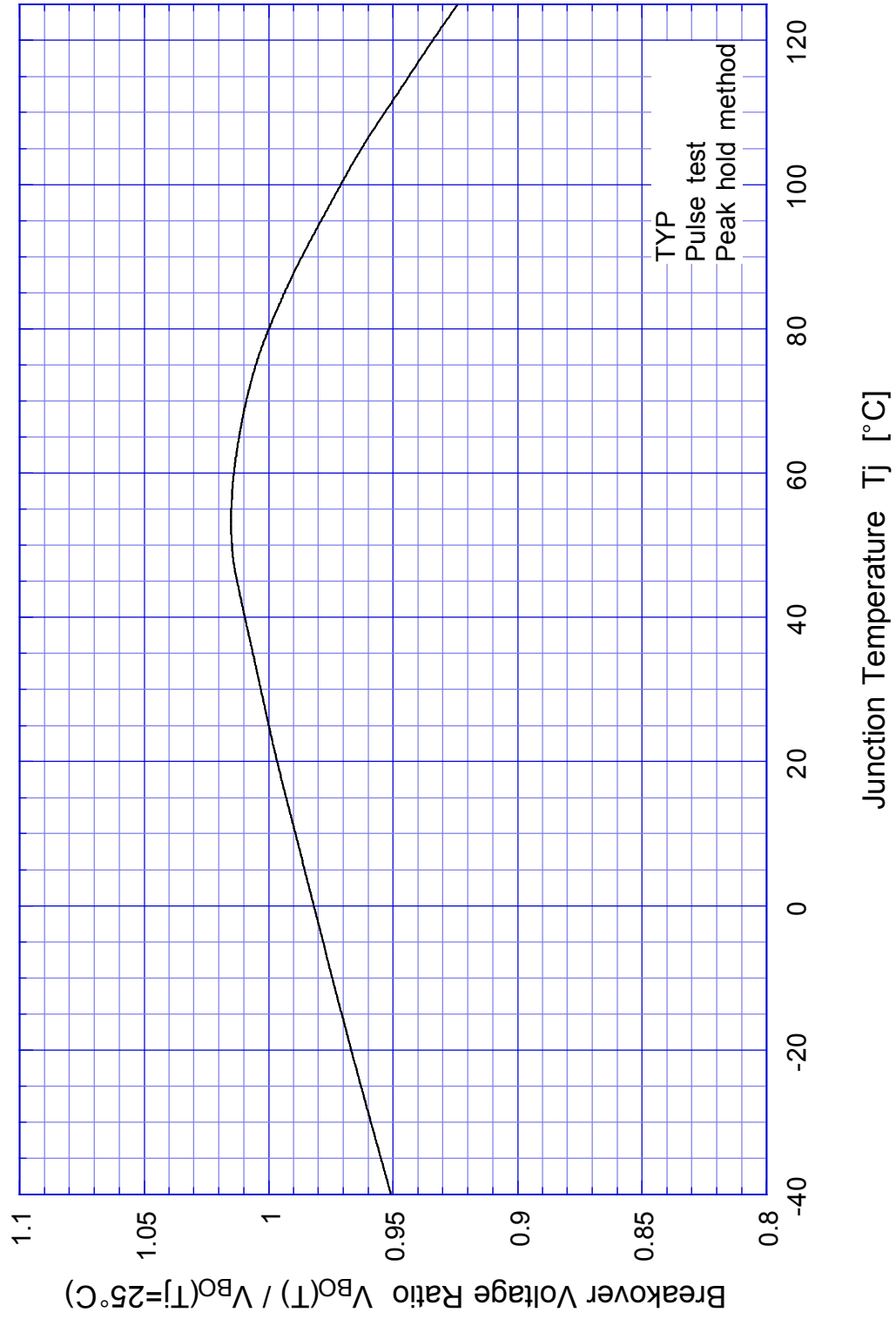
#### ● Electrical Characteristics (Tl=25°C)

Item	Symbol	Conditions	Ratings	Unit
Breakover Voltage	$V_{BO}$	Pulse measurement (Peak hold)	Min 130	V
Off-State Current	$I_{DRM}$	$V_D = V_{DRM}$	Max 10	$\mu$ A
Holding Current	$I_H$	Pulse measurement	Min 100	mA
On-State Voltage	$V_T$	$I_T = 2A$	TYP 1.15	V
Junction Capacitance	$C_j$	f = 1kHz OSC = 1V, $V_D = 50V$	Max 140	pF
Clamping Voltage	$V_{CL}$	dv/dt = 100V/ $\mu$ s	Max 195	V

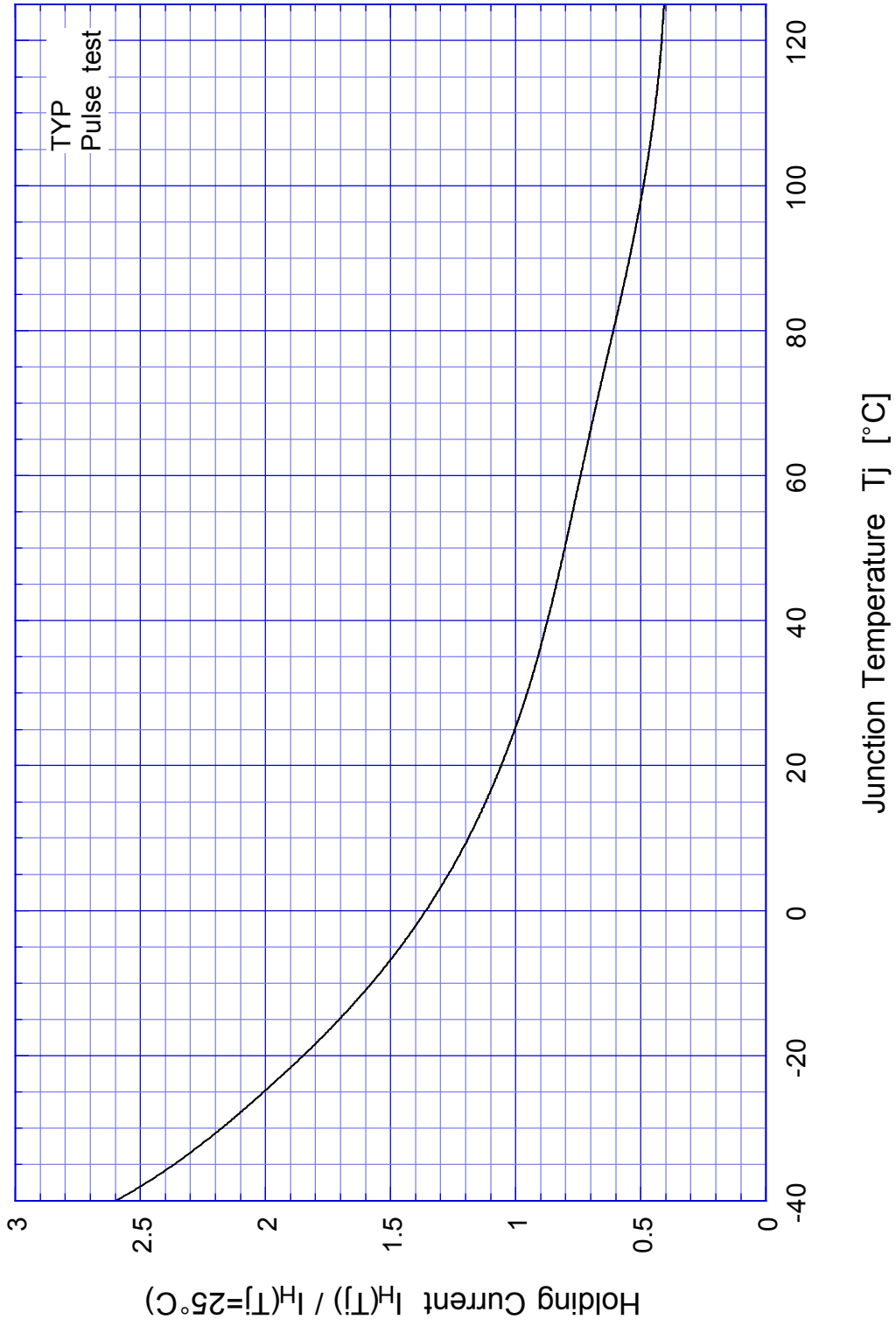
# KP10N14 On-State Voltage - On-State Current



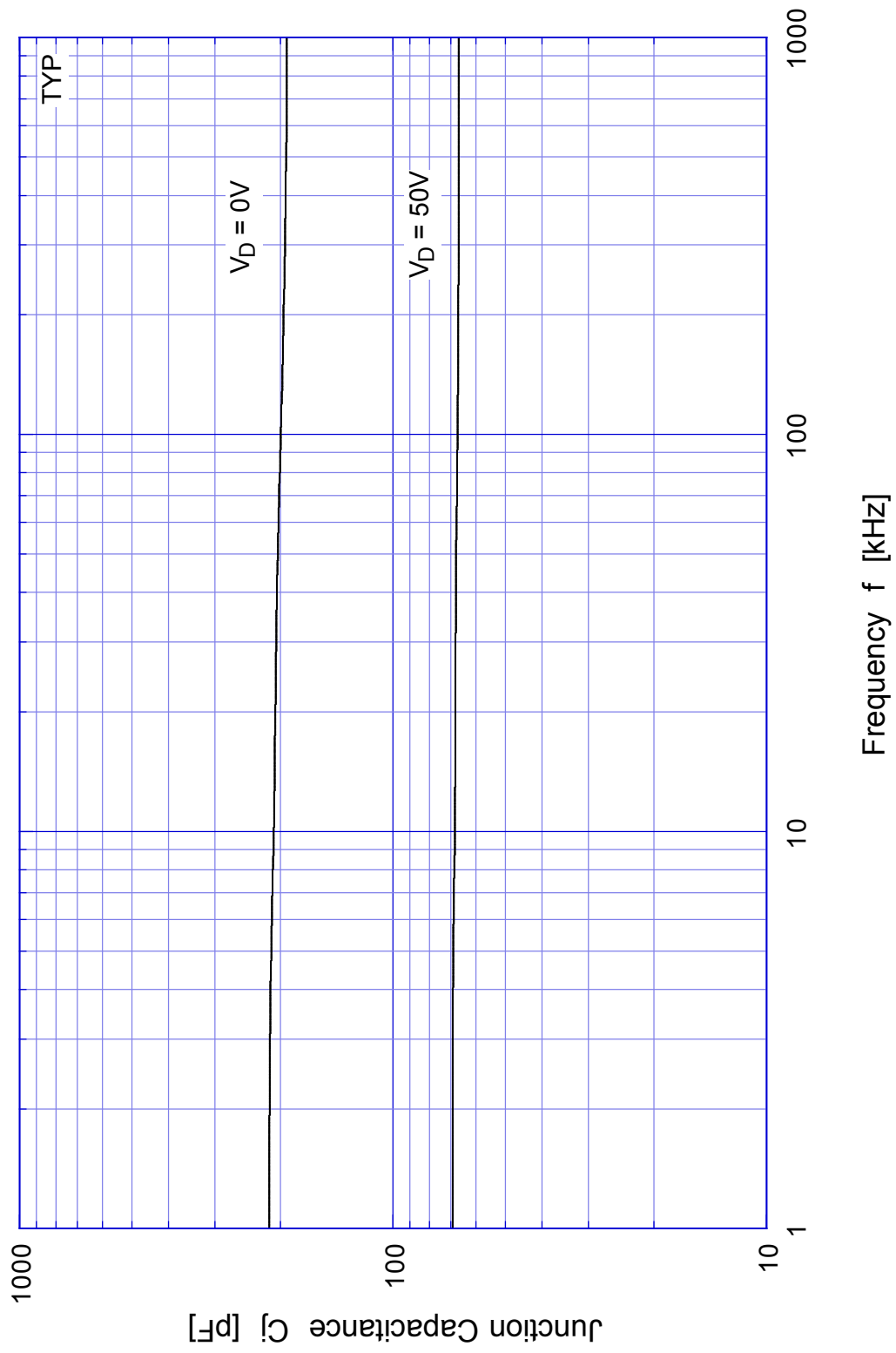
# KP10N14 Breakover Voltage - Junction Temperature



# KP10N14 Holding Current - Junction Temperature



# KP10N14 Junction Capacitance



# KP10N14 Junction Capacitance

